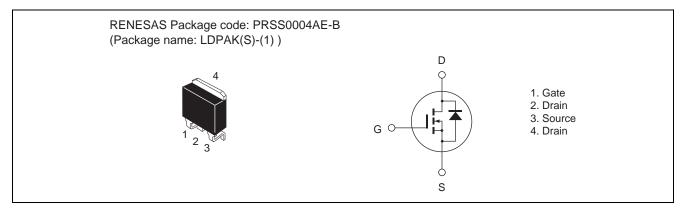


Silicon N Channel MOS FET High Speed Power Switching R07DS0487EJ0300 (Previous: REJ03G1488-0200) Rev.3.00 Jun 29, 2011

Features

- Low on-resistance
- $R_{DS(on)} = 0.385 \ \Omega \text{ typ.}$ (at $I_D = 7 \text{ A}$, $V_{GS} = 10 \text{ V}$, Ta = 25 °C)
- Low leakage current
- High speed switching

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$	
Item	Symbol	Ratings	Unit	
Drain to source voltage	V _{DSS}	500	V	
Gate to source voltage	V _{GSS}	±30	V	
Drain current	ID	14	А	
Drain peak current	Note1 ID (pulse)	42	А	
Body-drain diode reverse drain current	I _{DR}	14	А	
Body-drain diode reverse drain peak current	Note1 I _{DR (pulse)}	42	А	
Avalanche current	I _{AP} ^{Note3}	4	А	
Avalanche energy	E _{AR} ^{Note3}	0.88	mJ	
Channel dissipation	Pch Note2	100	W	
Channel to case thermal impedance	θch-c	1.25	°C/W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

Notes: 1. PW \leq 10 $\mu s,$ duty cycle \leq 1%

2. Value at Tc = 25°C

3. STch = 25° C, Tch $\leq 150^{\circ}$ C



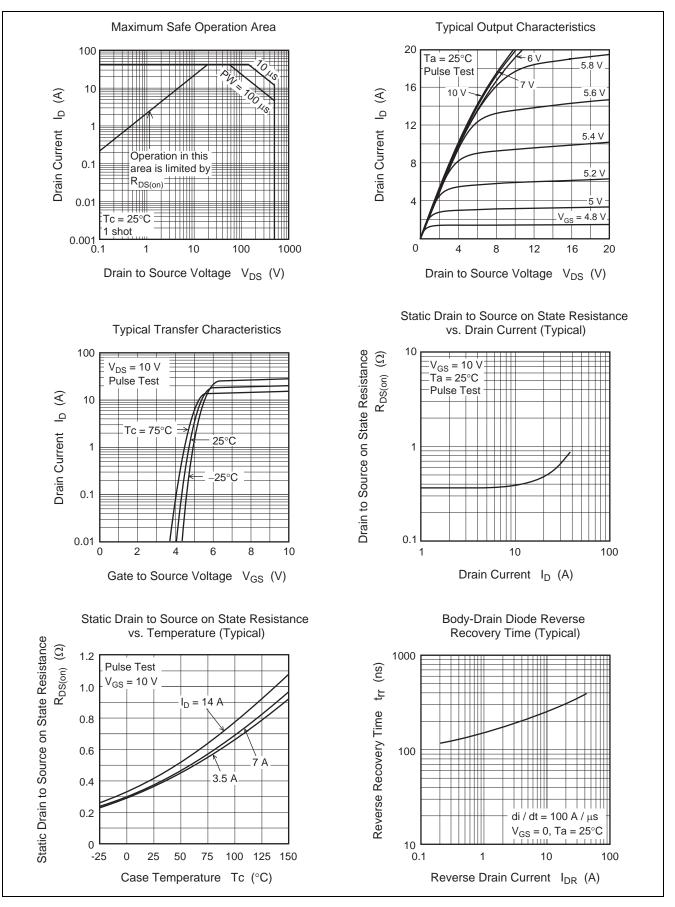
Electrical Characteristics

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V _{(BR)DSS}	500	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I _{DSS}	_	—	1	μΑ	$V_{DS} = 500 \text{ V}, \text{ V}_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS}=\pm 30~V,~V_{DS}=0$
Gate to source cutoff voltage	V _{GS(off)}	3.0	_	4.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	0.385	0.465	Ω	$I_D = 7 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
resistance						
Input capacitance	Ciss	_	1450	—	pF	V _{DS} = 25 V
Output capacitance	Coss	_	155	—	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	19	—	pF	
Turn-on delay time	t _{d(on)}	_	34	—	ns	I _D = 7 A
Rise time	tr	_	24	—	ns	$V_{GS} = 10 V$ $R_L = 35.7 \Omega$ $Rg = 10 \Omega$
Turn-off delay time	t _{d(off)}	_	86	—	ns	
Fall time	t _f	_	16	—	ns	
Total gate charge	Qg	_	38	—	nC	V _{DD} = 400 V
Gate to source charge	Qgs	_	8	_	nC	V _{GS} = 10 V I _D = 14 A
Gate to drain charge	Qgd	_	17	_	nC	
Body-drain diode forward voltage	V _{DF}	_	0.9	1.5	V	$I_F = 14 \text{ A}, V_{GS} = 0^{Note4}$
Body-drain diode reverse recovery time	t _{rr}	_	310	_	ns	$I_F = 14 \text{ A}, V_{GS} = 0$
						di _F /dt = 100 A/µs

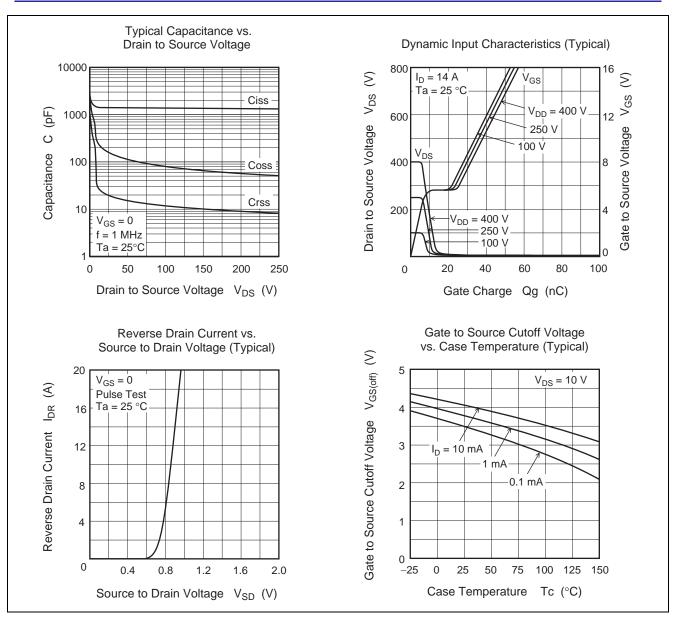
Notes: 4. Pulse test



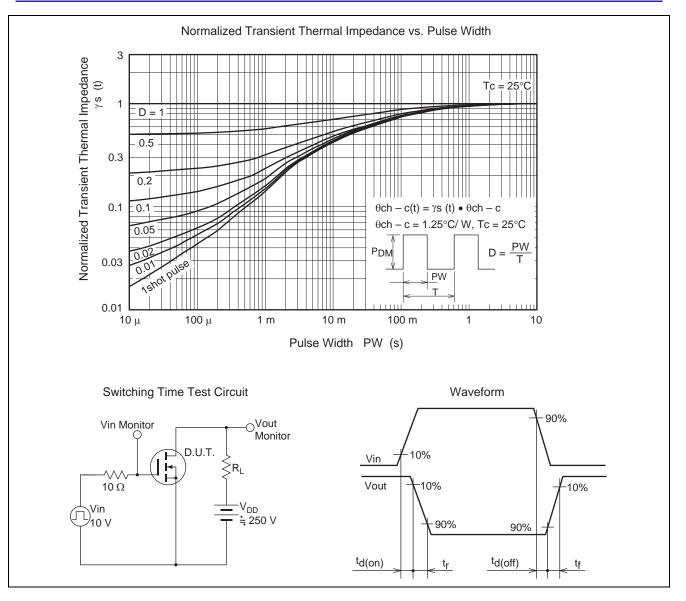
Main Characteristics





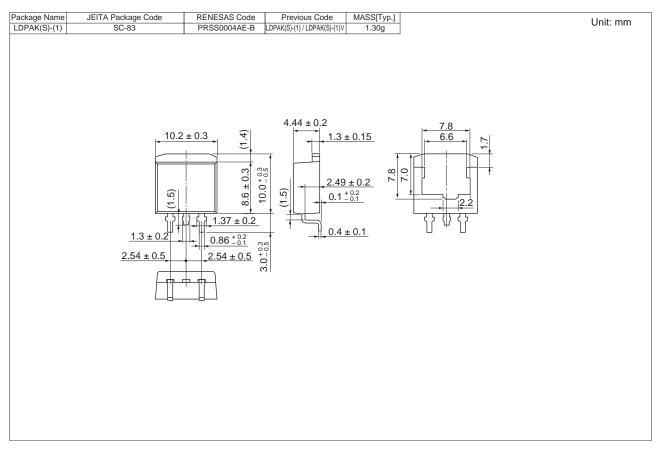








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK5013DPE-00-J3	1000 pcs	Taping



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